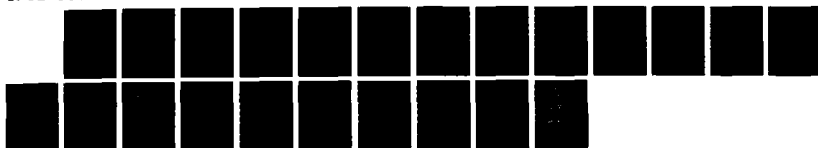
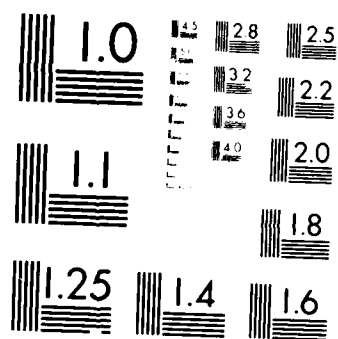


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Optical Technique for Increasing Fill Factor of Mosaic Arrays

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10 November 1987

Prepared for
SPACE DIVISION
AIR FORCE SYSTEMS COMMAND
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This report was submitted by The Aerospace Corporation, El Segundo, CA 90245, under Contract No. F04701-83-C-0084 with the Space Division, P.O. Box 92960, Worldway Postal Center, Los Angeles, CA 90009. It was reviewed and approved for The Aerospace Corporation by D.H. Phillips, Director, Electronics Research Laboratory.

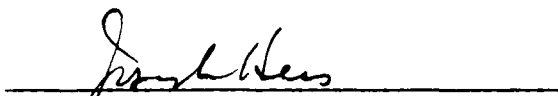
Lt Scott W. Levinson/YNS was the project officer for the Mission-Oriented Investigation and Experimentation (MOIE) Program.

This report has been reviewed by the Public Affairs Office (PAS) and is releasable to the National Technical Information Service (NTIS). At NTIS, it will be available to the general public, including foreign nationals.

This technical report has been reviewed and is approved for publication. Publication of this report does not constitute Air Force approval of the report's findings or conclusions. It is published only for the exchange and stimulation of ideas.



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REPORT DOCUMENTATION PAGE		READ INSTRUCTIONS BEFORE COMPLETING FORM
1. REPORT NUMBER SD-TR-87-54	2. GOVT ACCESSION NO.	3. RECIPIENT'S CATALOG NUMBER
4. TITLE (and Subtitle) OPTICAL TECHNIQUE FOR INCREASING FILL FACTOR OF MOSAIC ARRAYS		5. TYPE OF REPORT & PERIOD COVERED
		6. PERFORMING ORG. REPORT NUMBER TR-0083(3925-05)-1
7. AUTHOR(s) W. A. Garber, E. F. Cross, O. L. Gibb, G. D. Wiemokly, and I. J. Spiro		8. CONTRACT OR GRANT NUMBER(s) F04701-82-C-0083
9. PERFORMING ORGANIZATION NAME AND ADDRESS The Aerospace Corporation El Segundo, Calif. 90245		10. PROGRAM ELEMENT, PROJECT, TASK AREA & WORK UNIT NUMBERS
11. CONTROLLING OFFICE NAME AND ADDRESS Space Division Los Angeles Air Force Station Los Angeles, Calif. 90009		12. REPORT DATE 10 November 1987
		13. NUMBER OF PAGES 16
14. MONITORING AGENCY NAME & ADDRESS (if different from Controlling Office)		15. SECURITY CLASS. (of this report) Unclassified
		15a. DECLASSIFICATION/DOWNGRADING SCHEDULE
16. DISTRIBUTION STATEMENT (of this Report) Approved for public release; distribution unlimited.		
17. DISTRIBUTION STATEMENT (of the abstract entered in Block 20, if different from Report)		
18. SUPPLEMENTARY NOTES		
19. KEY WORDS (Continue on reverse side if necessary and identify by block number) CCD Array Infrared Imaging Fill Factor Enhancement Optical Technique Focal Plan Array Staring Array		
20. ABSTRACT (Continue on reverse side if necessary and identify by block number) A novel optical technique for improving the performance of focal plane staring arrays by increasing the fill factor ratio is described. The specific mosaics considered are 64 x 32 and 128 x 64 arrays of infrared detectors with infrared charge coupled devices (IRCCD) made from monolithic silicon. The video enhancement is accomplished by means of a refracting silicon faceplate that redirects focused image irradiance from nonsensitive CCD areas to the infrared detector elements. Operational theory and design		

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19. KEY WORDS (Continued)

20. ABSTRACT (Continued)

parameters for this unique faceplate construction are detailed. With the optimum faceplate configuration installed at the IRCCD front surface, a sensitivity increase of at least 150% is predicted from the analysis presented here.

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I. INTRODUCTION

Focal plane staring arrays consisting of Schottky barrier infrared detectors and infrared charge coupled devices (IRCCD) are currently under development for use in several remote sensing applications. These IRCCD arrays use monolithic silicon construction for sensing image irradiance in the optical field-of-view. The radiant intensity at each Schottky platinum-silicide (Pt-Si) detector is converted to an electronic charge that is integrated and read out by the charge coupled device (CCD) in the adjacent row. Although this type of image sensor has high response uniformity, large dynamic range, and excellent survivability characteristics, the elemental quantum efficiency and sensing area density are lower than is realizable from other staring mosaics. This report describes a novel optical technique that significantly improves the responsivity of Schottky IRCCD arrays by increasing the sensitive-area fill factor.

II. THEORY OF OPERATION

Improved array performance is attained through installation of an optical refracting faceplate at the IRCCD front surface. This faceplate must redirect the focused image irradiance that would normally fall on nonsensitive CCD areas adjacent to the Schottky detector elements. To accomplish this selective bending of optical rays, the primary faceplate design considerations are the front-surface geometry of the faceplate and the refractive index of the material. Specifically, it was determined that the faceplate should be made of a material with a high refractive index, such as silicon or germanium, with a one-dimensional scalloped front-surface pattern extending over each row of detectors. The physical dimensions of current IRCCD chips were used to perform the calculations detailed in the following section to determine realizable faceplate dimensions for collecting optimum irradiance at the Schottky detectors.

III. FACEPLATE DESIGN

The following faceplate design is operational with the 64×32 IRCCD mosaics (2048 detectors). This 64×32 array is 0.64 cm square, with each detector measuring $59 \times 55 \mu\text{m}$. The $101\text{-}\mu\text{m}$ gap between each 64-element row is occupied by the associated CCDs. Figure 1 shows these dimensions for the 2048-element configuration.

The special silicon faceplate installed on the Schottky IRCCD chip should have a scalloped front surface to optimize irradiance collection, and an optically flat back surface to maximize transmission efficiency. This analysis uses F1.2 optics to focus imagery onto the IRCCD chip. For such a fast optical system, the angular cone of image irradiance extends over a $\pm 22.6\text{-deg}$ range. On the basis of this angular range and IRCCD element dimensions, the required front-surface arc radius and retinæ thickness (faceplate plus IRCCD thickness) for maximum optical collection can be calculated from the following equations:

$$d(A)_{\max} = w/2 \sqrt{n_2^2(4F^2 + 1) - 1} \quad (1)$$

$$X_B = \left[d(B)_{\max} - \frac{(w + s)(1 - \cos\theta_a)}{2 \sin\theta_a} \right] \tan \left\{ \sin^{-1} \left[\frac{\sin(\theta_F - \theta_a)}{n_2} \right] + \theta_a \right\} - s/2 \quad (2)$$

$$X_C = \left[d(C)_{\max} - \frac{(w + s)(1 - \cos\theta_a)}{2 \sin\theta_a} \right] \tan \left\{ \sin^{-1} \left[\frac{\sin(\theta_F - \theta_a)}{n_2} \right] - \theta_a \right\} - s/2 \quad (3)$$

The derivation of these faceplate parameter equations is contained in the Appendix of Reference 3.

The optical paths for extreme rays directed through the collecting faceplate and IRCCD front surface to each Schottky Pt-Si junction are shown in Figure 2. Since these extreme rays can be redirected to fall on an active detector area, all rays at lesser angles also reach the sensing elements.

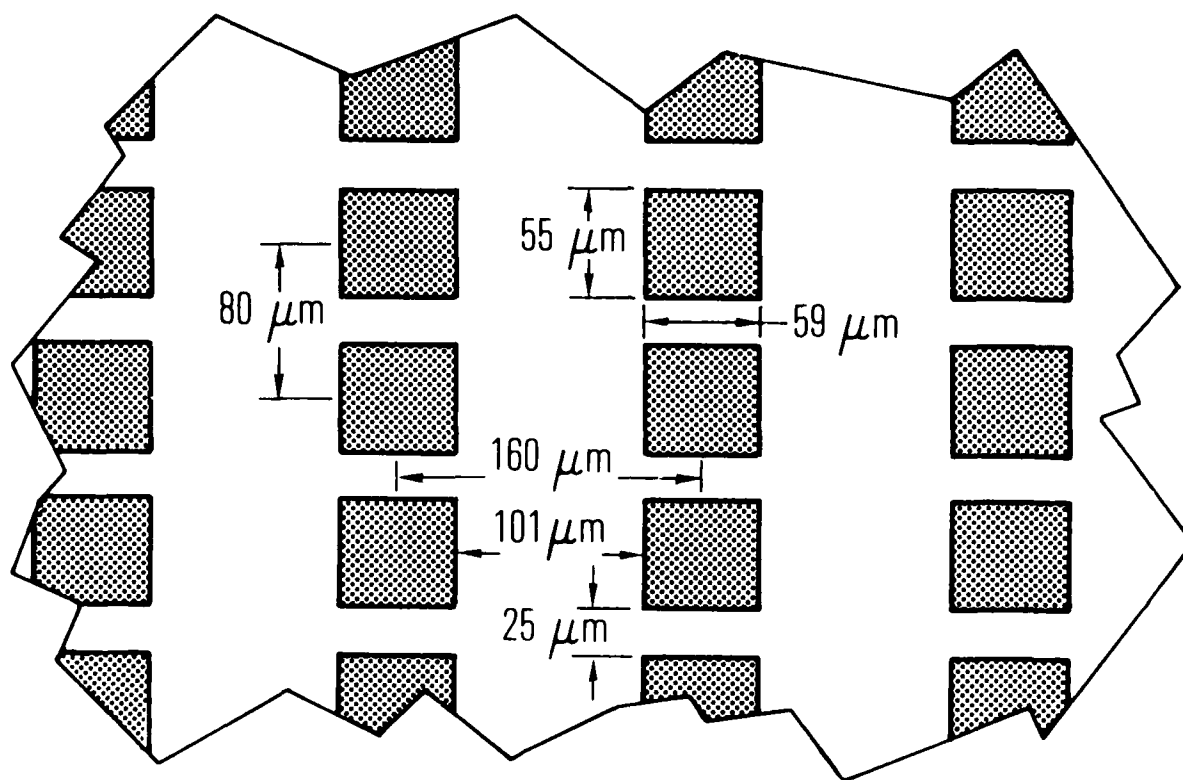


Figure 1. Elemental dimensions for 64 \times 32 Schottky IRCCD mosaic

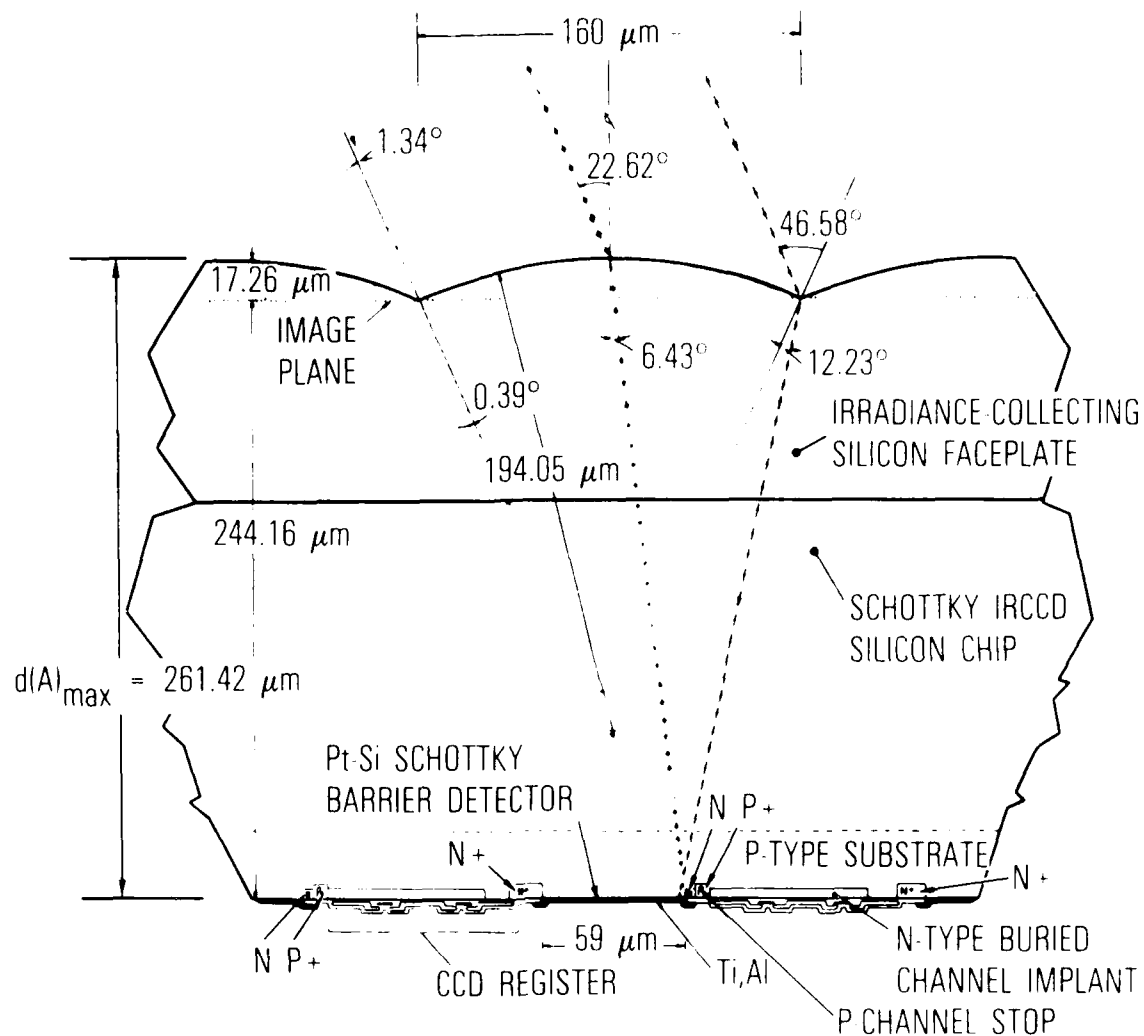


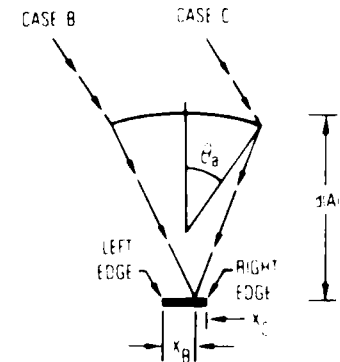
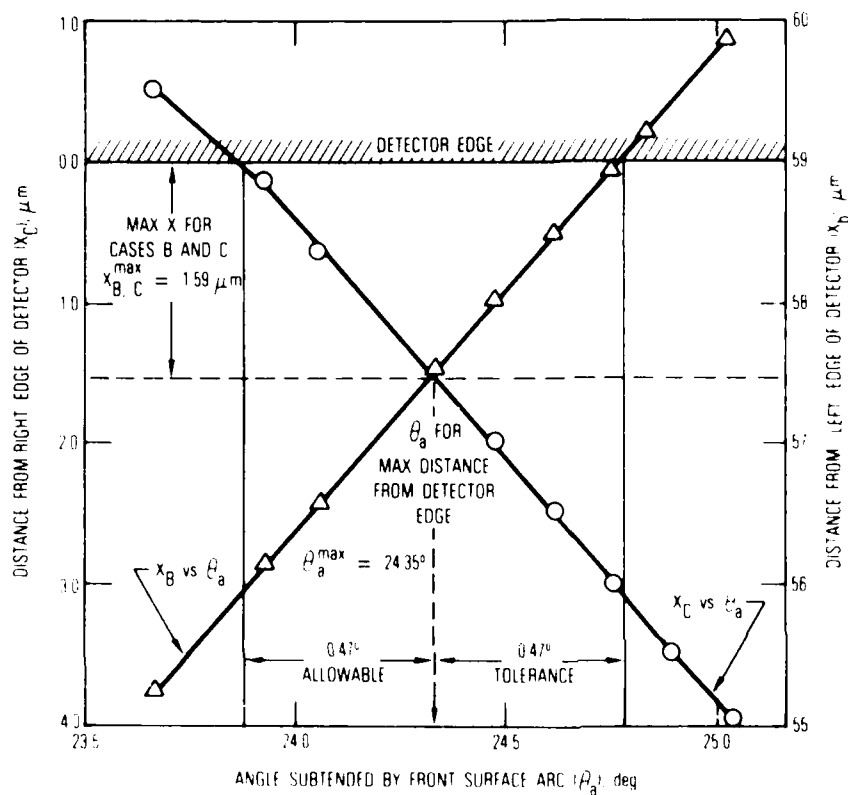
Figure 2. Optical ray tracing diagram for collecting faceplate and 64 × 32 IRCCD mosaic. The extreme rays shown are for an F1.2 system and are symmetric about the center line.

By graphic method or analytical calculations, the faceplate arc radii and retinae thickness for optimum irradiance collection are found to be 194.05 and 261.42 μm , respectively. These calculations were verified by John W. Ellinwood (Reference 2) using Fresnel diffraction analysis.

Each arc radius can be defined in terms of the front-surface angular arc (θ_a) subtended by the 160- μm chord over each sensing element of the 64×32 array.

In Figure 3 the optimum value and allowable tolerance for θ_a is graphically found to be 24.35 ± 0.47 deg as determined by the intersection of the plotted extreme ray distances from the detector edge (X_B and X_C). This figure also describes the variation in X_B and X_C as a function of faceplate θ_a . These results were also verified with a computerized ray tracing program. Figure 4 is an illustration of the special faceplate design as installed on a typical 64×32 Schottky IRCCD array.

The second collecting faceplate design is operational with the 128×64 array (0.64 cm square), with each detector measuring 50×40 μm . The 70- μm gaps between the 128-element rows are occupied by the associated CCDs. These dimensions are diagrammed in Figure 5 for the 8192-element configuration. Using graphic and analytical methods described above, the faceplate arc radii and retinae thickness for optimum irradiance collection are found to be 164.3 and 221.54 μm , respectively. The optimum arc radius, defined in terms of the θ_a , is graphically found in Figure 6 to be 21.43 ± 0.37 deg, as determined by coincidence of the X_B and X_C curves. This figure also describes the variation in X_B and X_C as a function of faceplate θ_a .



FIXED PARAMETERS
SILICON FACEPLATE

64 x 32 MOSAIC
 $n = 3.43$ $w = 59 \mu\text{m}$

CALCULATED FROM EQUATION

$$|A|_{\text{max}} = \frac{w}{r} \sqrt{\frac{r}{\lambda}}$$

FOR $F = 1$,

$$|A|_{\text{max}}^{F1.2} = 261.4 \mu\text{m}$$

Figure 3. Focused irradiance distance from detector edge (X_B , X_C) vs. faceplate front surface arc (θ_a) for 64 x 32 Schottky mosaic

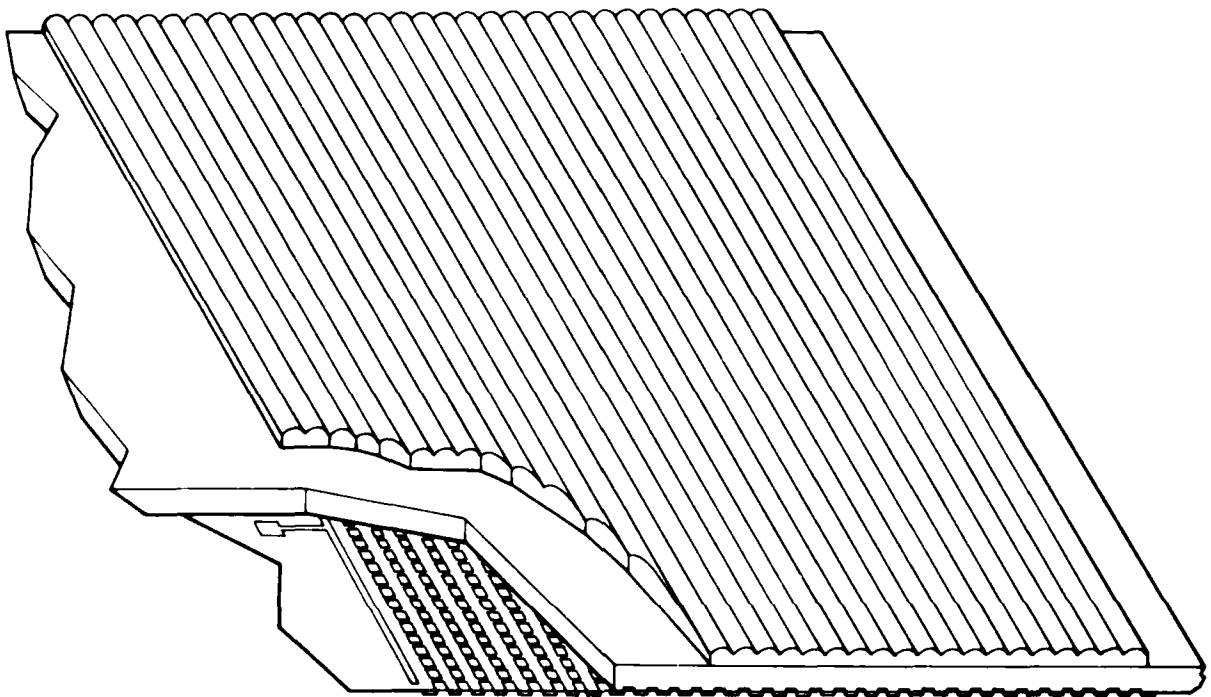


Figure 4. Schottky IRCCD mosaic with faceplate

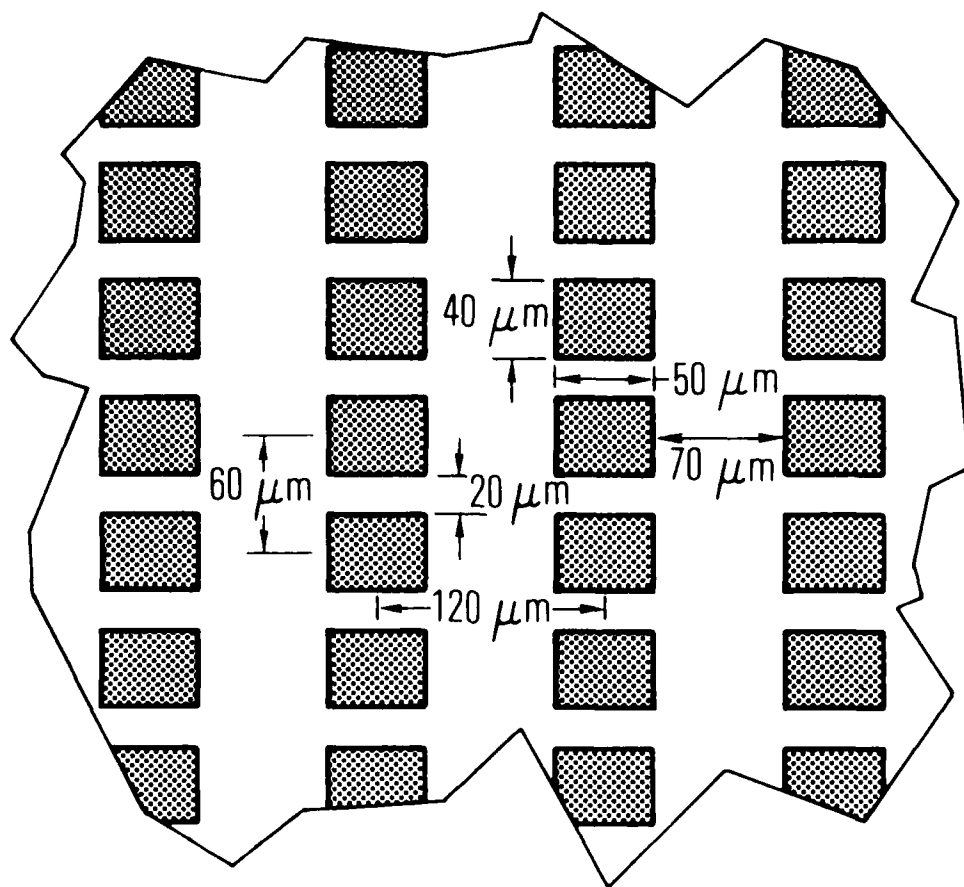
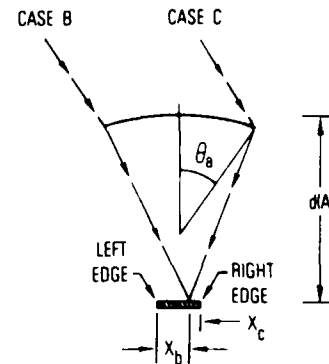
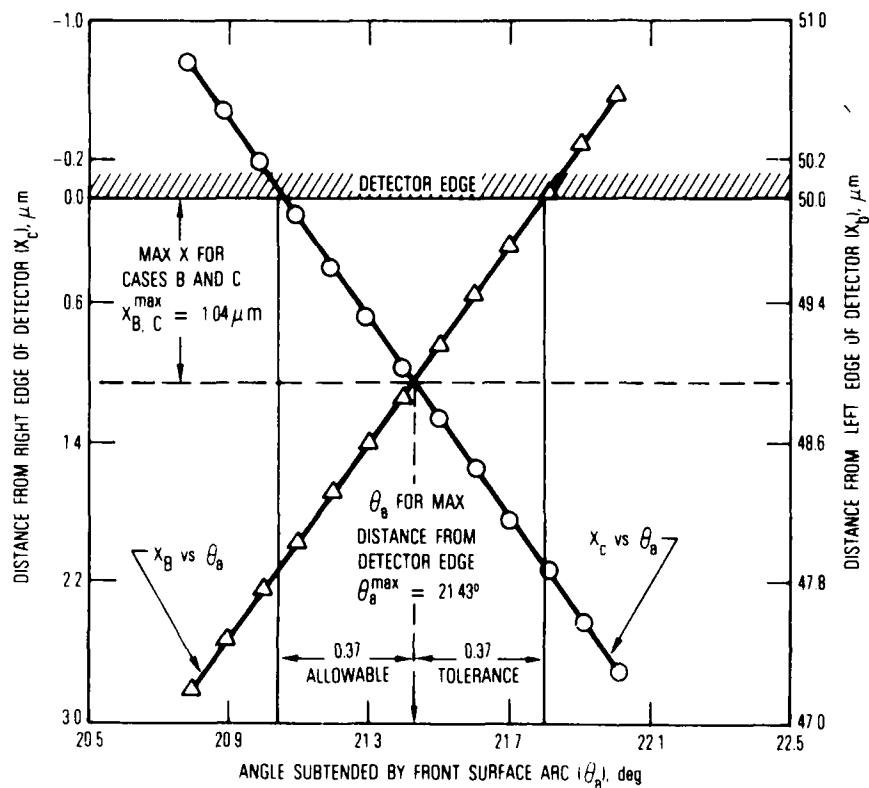


Figure 5. 64 x 128 detector array



**FIXED PARAMETERS
SILICON FACEPLATE**

128 x 64 MOSAIC
 $n = 3.43$, $w = 50 \mu m$

CALCULATED FROM EQUATION

$$dIAI_{max} = \frac{wn}{2} \sqrt{4f^2 + 1}$$

for $f = 12$

$$dIAI_{max}^{f12} = 221.54 \mu m$$

Figure 6. Focused irradiance distance from detector edge (X_B , X_C) vs. faceplate front surface arc (θ_a) for 128 x 64 Schottky mosaic

IV. FACEPLATE CONSTRUCTION

The silicon faceplate geometry can be fabricated with current state-of-the-art technology. One technique for fabricating the front-surface arcs would use precision diamond machining processes. However, construction difficulties could occur if the required faceplate thickness is below 70 μm . With slower optics the required faceplate thickness can be increased proportionally, as shown in Figure 7. It is also probable that faceplate thickness can be increased by reducing IRCCD chip thickness. If a sophisticated indexing technique could be devised, it may be possible to fabricate the curved surface geometry directly onto the IRCCD front surface.

To optimize performance of this composite focal plane retina, both faceplate surfaces and the front IRCCD chip surface should be antireflection coated for the spectral region of interest. In this manner signal irradiance losses between the outside silicon faceplate surface and the Schottky infrared detectors can be reduced by 50%. A germanium faceplate with similar geometry could be used to provide the optical collection, since this material has a refractive index of 4.0. Because of this higher index value, germanium produces greater optical path bending than silicon for the same faceplate thickness. Two disadvantages of such an approach are that (1) germanium faceplates at the required thicknesses are not easily fabricated because the material is very brittle, and (2) aligning the faceplate with the IRCCD chip is more complex because of differing thermal coefficients over the ambient-to-77 K temperature range.

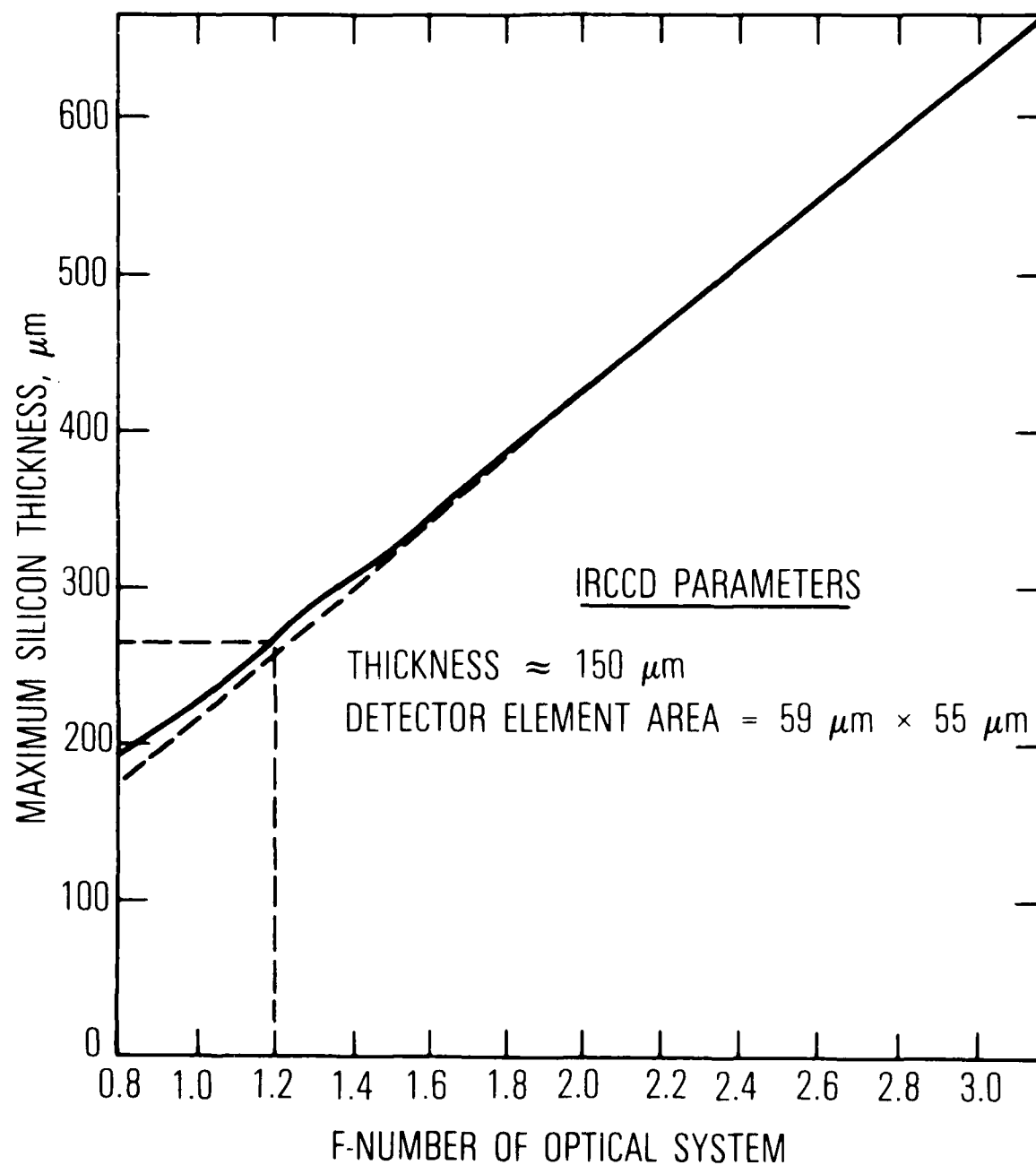


Figure 7. F number of optical system vs. maximum allowable silicon retina thickness

V. CONCLUSIONS

In summary, this novel optical technique can increase the sensitivity of current Pt-Si Schottky barrier mosaics by at least a factor of 1-1/2. The special silicon faceplate can be fabricated by means of state-of-the-art optical replication techniques. Since the mosaic and faceplate are both made of silicon, they remain aligned and perform as a single unit when cycled between ambient temperature and the 77-K operating temperature. The faceplate can also enhance performance of focal plane arrays in the specific design areas enumerated below:

1. By optically channeling signal irradiance from nonsensitive areas on the image plane, detector size, number, and density can be set up for optimum performance, with sensitive surface percentage becoming a less critical factor.
2. This silicon faceplate is designed to accommodate an F1.2 optical system, but equivalent percentage increases in sensitivity can also be achieved with slower (large F-numbers) optics without requiring any modification.
3. The improvement in sensitivity does not adversely affect the spectral response or dynamic range of detectors.
4. Detection probabilities for subaperture target images on the focal plane are significantly increased, because dead-zone areas between the horizontal sensing elements are eliminated by the collecting faceplate. Only the much smaller nonsensitive areas between adjacent vertical detectors remain unchanged.
5. With the increased fill factor, dead-zone area becomes a less significant design parameter in the construction restraint on focal plane electronics. By easing design criteria in this manner, more reliable and effective fabrication techniques can be adopted to improve IRCCD performance.

Although this novel technique has been specifically tailored for current Pt-Si Schottky barrier mosaics, it is applicable to other focal plane arrays. This approach would be especially beneficial to arrays where the sensitive area of the element area constitutes less than 50 percent of the image plane.

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As a result, the model for the β function can be interpreted as a fixed point of the RG flow. The fixed point is reached when the coupling constant β is small, and the theory is in the Gaussian fixed point. The fixed point is reached when the coupling constant β is small, and the theory is in the Gaussian fixed point.

19. J. A. Ivin, *Chemical Reactions of Olefins*, Butterworths, London, 1969, p. 107.

At present, the following fields are being actively investigated: Atoms, simple chemical reactions, intermolecular interactions, molecular structure, state-specific chemical reactions, and isotopic effects in chemical reactions; sensor, optoelectronic, and view recognition; atmospheric chemistry; laser chemistry, laser optoelectronics, solid-state physics, battery electrochemistry, space vacuum and radiation effects on materials, adsorption and surface phenomena, thermionic emission, photo-sensitive materials and detectors, atomic frequency standards, and environmental chemistry.

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Mathematical models of the human body are used to estimate the effect of the mechanical properties of the body on the risk of injury. The models are based on the assumption that the body is a system of interconnected parts, each with its own mechanical properties. The models are used to estimate the risk of injury by comparing the predicted mechanical properties of the body with the known mechanical properties of the body. The models are used to estimate the risk of injury by comparing the predicted mechanical properties of the body with the known mechanical properties of the body. The models are used to estimate the risk of injury by comparing the predicted mechanical properties of the body with the known mechanical properties of the body.

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